

ZXTP25040DFH 40V SOT23 PNP medium power transistor

Summary

 $BV_{CEO} > -40V$

 $BV_{ECO} > -3V$;

 $I_{C(CONT)} = -3A$

 $R_{CE(sat)} = 55 \text{ m}\Omega$;

 $V_{CE(sat)} < -85mV @ 1A;$

 $P_{D} = 1.25W$



Description

Advanced process capability and package design have been used to maximize the power handling and performance of this small outline transistor. The compact size and ratings of this device make it ideally suited to applications where space is at a premium.

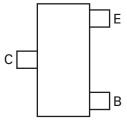
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Features

- High power dissipation SOT23 package
- · High peak current
- · Low saturation voltage
- 3V reverse blocking voltage

Applications

- · MOSFET and IGBT gate driving
- DC DC converters
- · Motor drive
- · High side driver



Pinout - top view

Ordering information

Device	Reel size (inches)	Tape width	Quantity per reel
ZXTP25040DFHTA	7	8mm	3000

Device marking

024

Absolute maximum ratings

Parameter	Symbol	Limit	Unit	
Collector-base voltage	V _{CBO}	-45	V	
Collector-emitter voltage (forward blocking)	V _{CEO}	-40	V	
Emitter-collector voltage (reverse blocking)	V _{ECO}	-3	V	
Emitter-base voltage	V _{EBO}	-7	V	
Continuous collector current (b)	I _C	-3	Α	
Peak pulse current	I _{CM}	-9	Α	
Power dissipation at T _A =25°C ^(a) linear derating factor	P _D	0.73 5.84	W mW/°C	
Power dissipation at T _A =25°C ^(b) linear derating factor	P _D	1.05 8.4	W mW/°C	
Power dissipation at T _A =25°C ^(c) linear derating factor	P _D	P _D 1.25 9.6		
Power dissipation at T _A =25°C ^(d) linear derating factor	P _D	1.81 14.5	W mW/°C	
Operating and storage temperature range	T _j , T _{stg}	-55 to 150	°C	

Thermal resistance

Parameter	Symbol	Limit	Unit
Junction to ambient ^(a)	$R_{\Theta JA}$	171	°C/W
Junction to ambient (b)	$R_{\Theta JA}$	119	°C/W
Junction to ambient (c)	$R_{\Theta JA}$	100	°C/W
Junction to ambient (d)	$R_{\Theta JA}$	69	°C/W

NOTES:

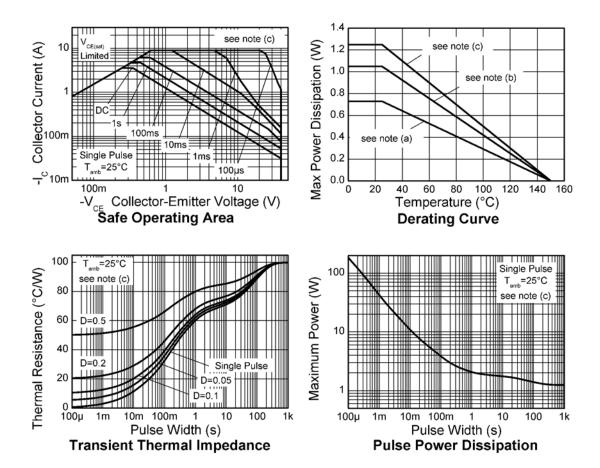
⁽a) For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

⁽b) Mounted on 25mm x 25mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.

⁽c) Mounted on 50mm x 50mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.

⁽d) As (c) above measured at t<5sec.

Characteristics



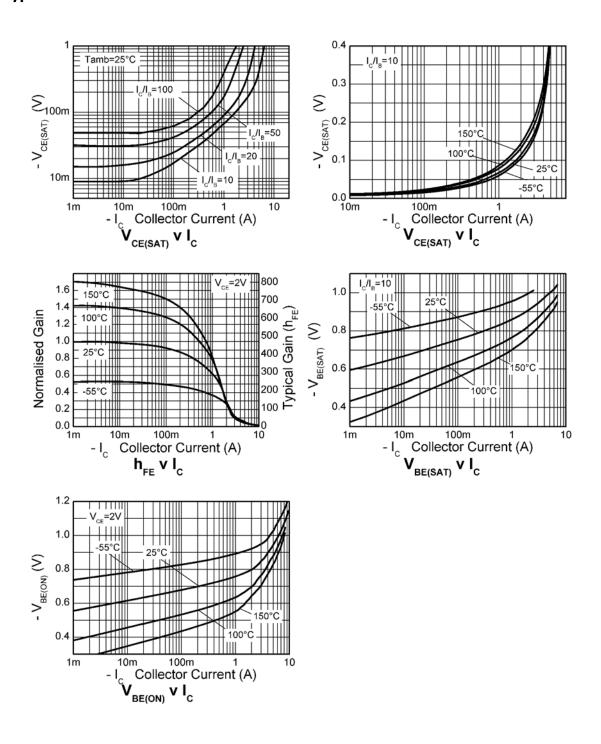
Electrical characteristics (at $T_{AMB} = 25^{\circ}C$ unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CBO}	-45	-75		V	I _C = -100μA
Collector-emitter breakdown voltage (base open)	BV _{CEO}	-40	-65		V	I _C = -10mA ^(*)
Emitter-collector breakdown voltage (reverse blocking)	BV _{ECO}	-3	-8.7		V	I _E = -100uA
Emitter-base breakdown voltage	BV _{EBO}	-7	-8.2		V	$I_E = -100 \mu A$
Collector cut-off current	I _{CBO}		<-1	-50 -0.5	nA μA	$V_{CB} = -45V$ $V_{CB} = -45V$, $T_{amb} = 100$ °C
Emitter cut-off current	I _{EBO}		<-1	-50	nA	V _{EB} = -5.6V
Collector-emitter saturation	V _{CE(sat)}		-170	-260	mV	I _C = -1A, I _B = -20mA ^(*)
voltage			-65	-85	mV	$I_C = -1A$, $I_B = -100 \text{mA}^{(*)}$
			-165	-220	mV	$I_C = -3A$, $I_B = -300 \text{mA}^{(*)}$
Base-emitter saturation voltage	V _{BE(sat)}		-930	-1000	mV	$I_C = -3A$, $I_B = -300 \text{mA}^{(*)}$
Base-emitter turn-on voltage	V _{BE(on)}		-830	-900	mV	$I_C = -3A$, $V_{CE} = -2V^{(*)}$
Static forward current	h _{FE}	300	450	900		I _C = -10mA, V _{CE} = -2V ^(*)
transfer ratio		200	300			$I_C = -1A$, $V_{CE} = -2V^{(*)}$
		30	60			$I_C = -3A$, $V_{CE} = -2V^{(*)}$
Transition frequency	f _T		270		MHz	I _C = -50mA, V _{CE} = -10V f = 100MHz
Output capacitance	C _{OBO}		17.4		рF	V _{CB} = -10V, f = 1MHz ^(*)
Turn-on time	t _(on)		75.5		ns	$V_{CC} = -15V. I_C = -750mA,$ $I_{B1} = I_{B2} = -15mA.$
Turn-off time	t _(off)		320		ns	

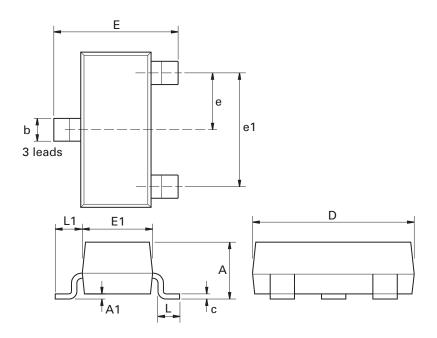
NOTES:

(*) Measured under pulsed conditions. Pulse width \leq 300 μ s; duty cycle \leq 2%.

Typical characteristics



Package outline - SOT23



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
Α	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	Е	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
С	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95	NOM	0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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